



**Capsule Thyristor**

## Line Thyristor

### SKT 1000

#### Features

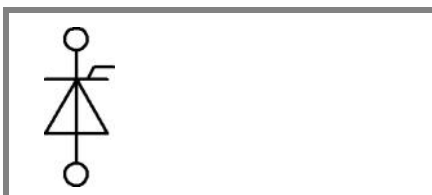
- Hermetic metal case with ceramic insulator
- Capsule package for double sided cooling
- International standard case
- Off-state and reverse voltages up to 2800 V
- Amplifying gate

#### Typical Applications

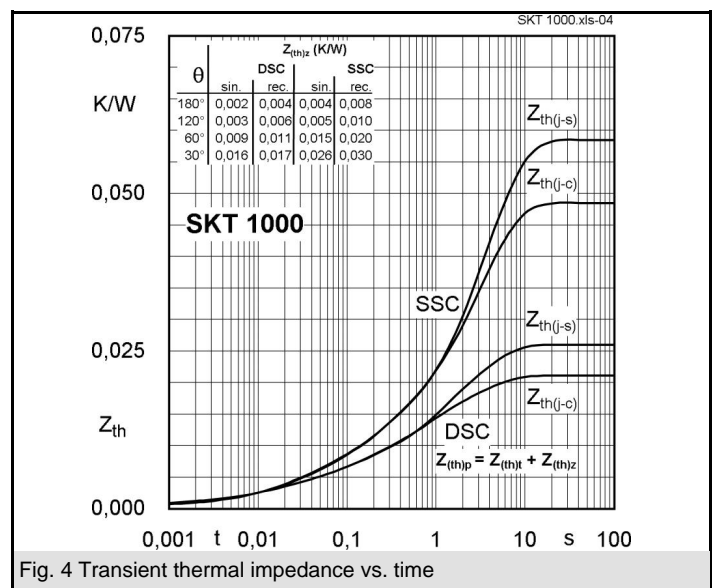
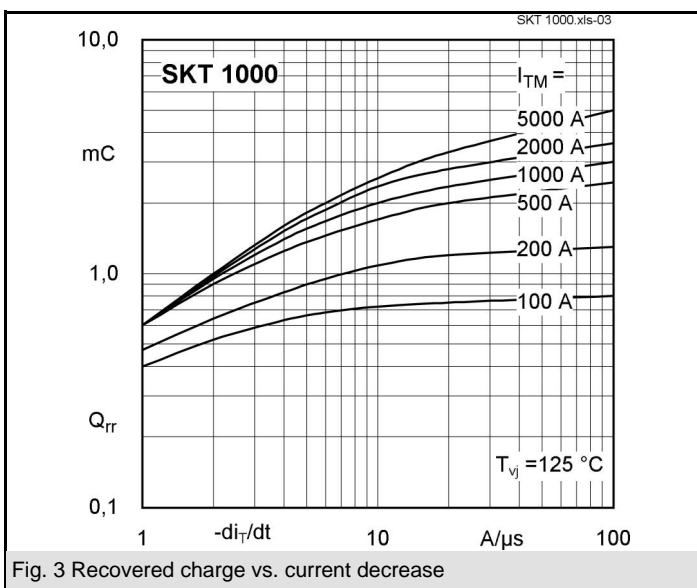
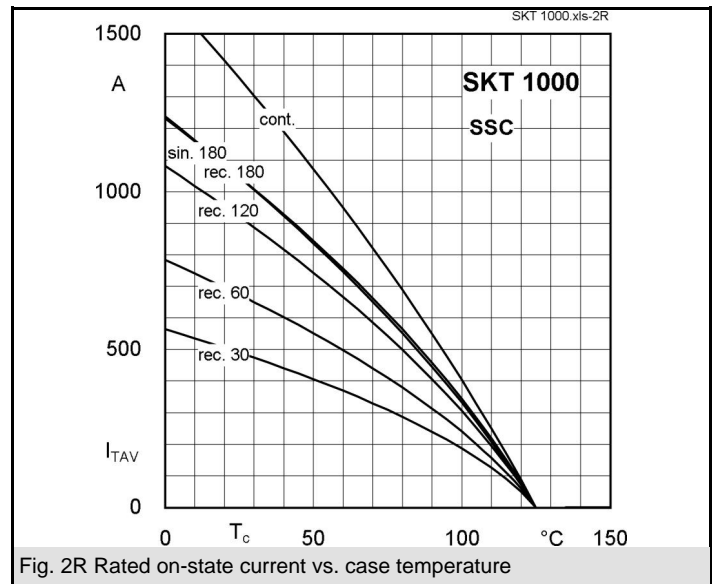
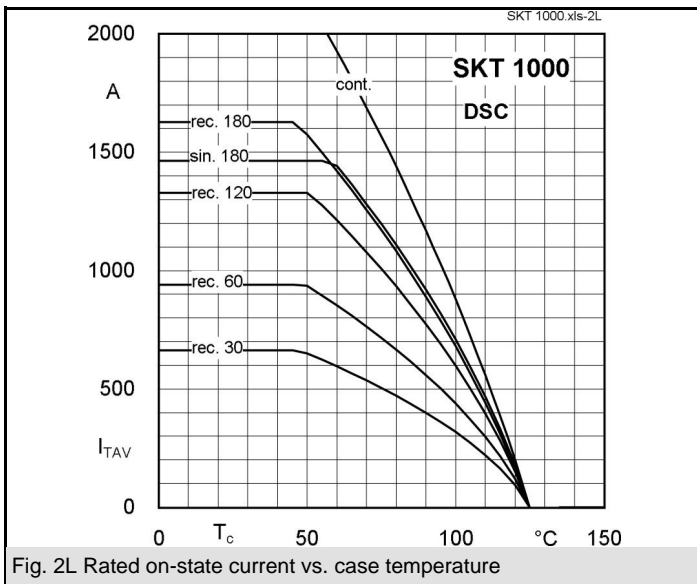
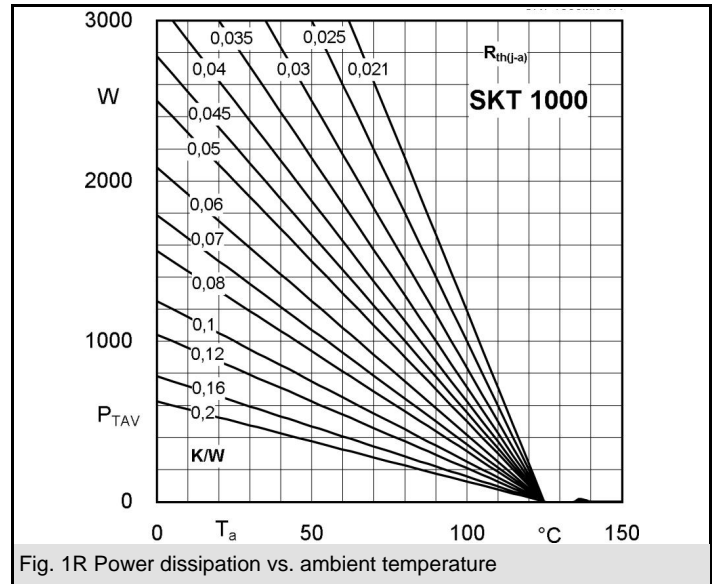
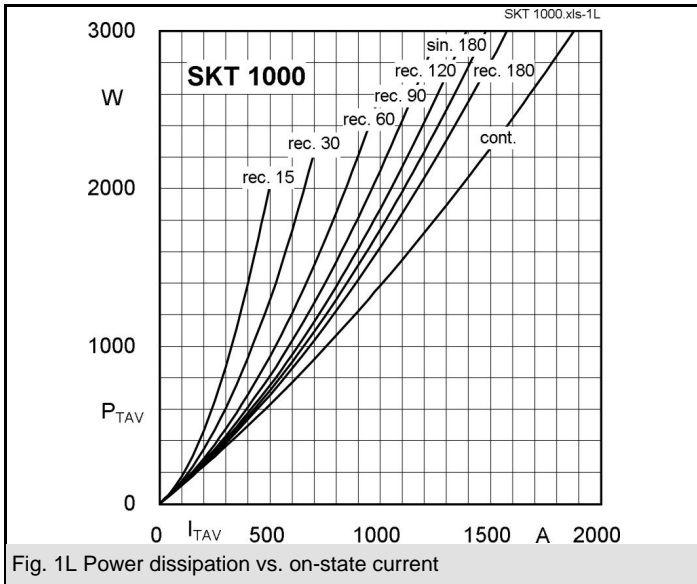
- DC motor control (e. g. for machine tools)
- Controlled rectifiers (e. g. for battery charging)
- AC controllers (e. g. for temperature control)
- Recommended snubber network e. g. for  $V_{VRMS} \leq 400$  V:  
 $R = 33 \Omega / 32$  W,  $C = 1 \mu F$

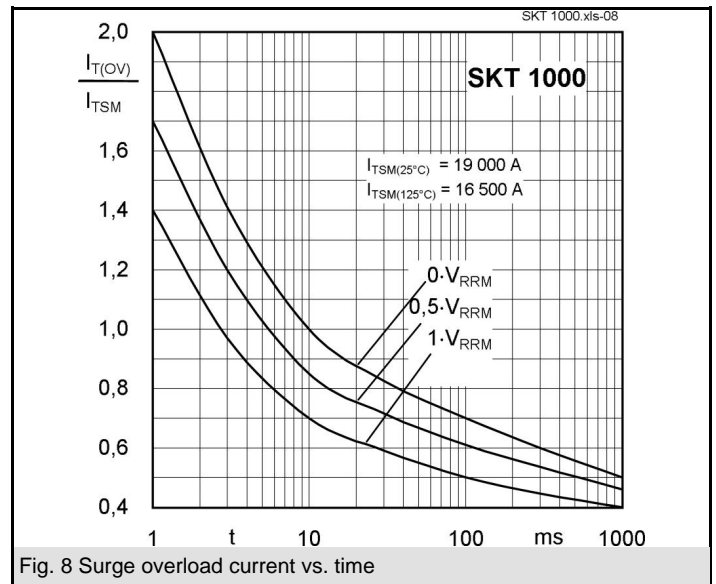
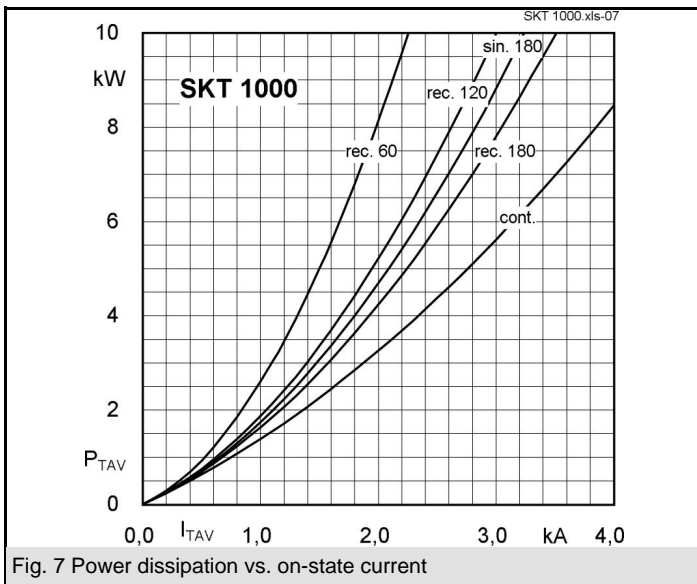
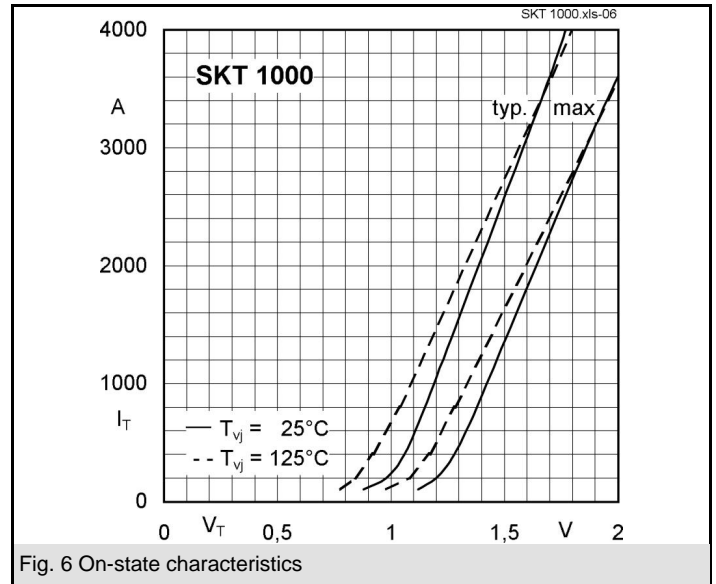
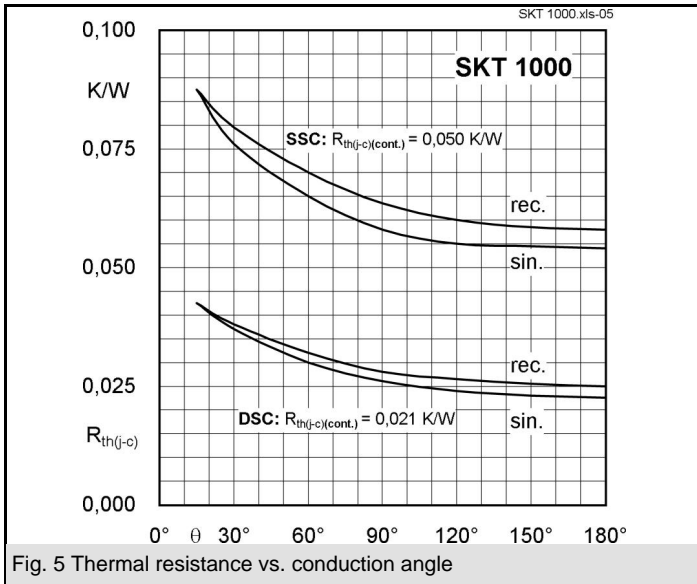
| $V_{RSM}$<br>V | $V_{RRM}, V_{DRM}$<br>V | $I_{TRMS} = 2300$ A (maximum value for continuous operation)<br>$I_{TAV} = 1000$ A (sin. 180; DSC; $T_c = 85$ °C) |  |
|----------------|-------------------------|---|--|
| 1300           | 1200                    | SKT 1000/12E  |  |
| 1700           | 1600                    | SKT 1000/16E  |  |
| 2300           | 2200                    | SKT 1000/22EL2  |  |
| 2700           | 2600                    | SKT 1000/26EL2  |  |
| 2900           | 2800                    | SKT 1000/28EL2  |  |

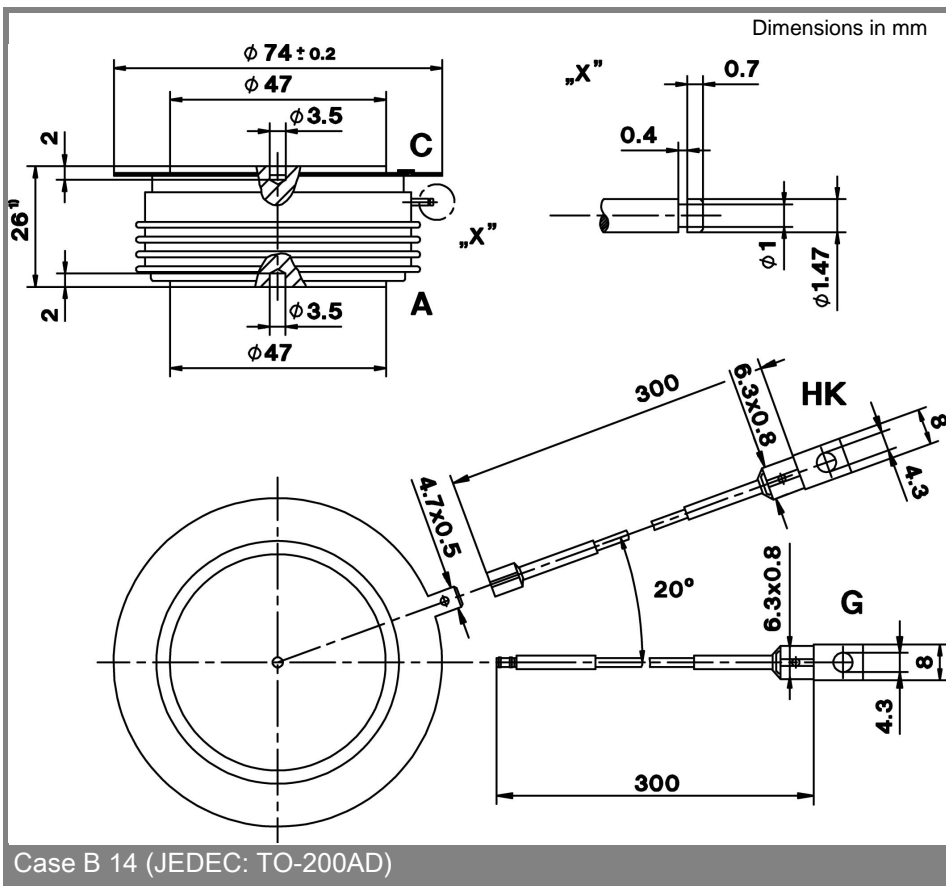
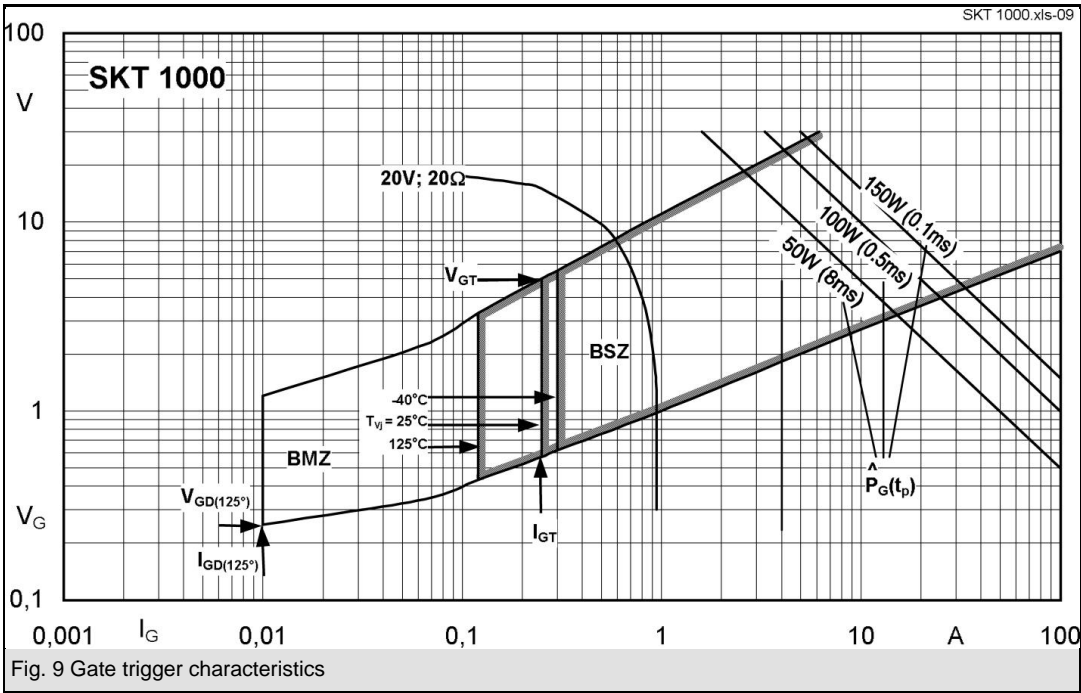
| Symbol           | Conditions  | Values         | Units            |
|------------------|---|----------------|------------------|
| $I_{TAV}$        | sin. 180; $T_c = 100$ (85) °C                           | 710 (1000)     | A                |
| $I_D$            | 2 x P8/180; $T_a = 45$ °C; B2 / B6                      | 360 / 500      | A                |
|                  | 2 x P8/180F; $T_a = 35$ °C; B2 / B6                     | 1250 / 1750    | A                |
| $I_{RMS}$        | 2 x P8/180; $T_a = 45$ °C; W1C                          | 400            | A                |
| $I_{TSM}$        | $T_{vj} = 25$ °C; 10 ms                                 | 19000          | A                |
|                  | $T_{vj} = 125$ °C; 10 ms                                | 16500          | A                |
| $i^2t$           | $T_{vj} = 25$ °C; 8,3 ... 10 ms                         | 1800000        | A <sup>2</sup> s |
|                  | $T_{vj} = 125$ °C; 8,3 ... 10 ms                        | 1360000        | A <sup>2</sup> s |
| $V_T$            | $T_{vj} = 25$ °C; $I_T = 3600$ A                        | max. 2         | V                |
| $V_{T(TO)}$      | $T_{vj} = 125$ °C                                       | 1,14           | V                |
| $r_T$            | $T_{vj} = 125$ °C                                       | 0,243          | mΩ               |
| $I_{DD}; I_{RD}$ | $T_{vj} = 125$ °C; $V_{RD} = V_{RRM}; V_{DD} = V_{DRM}$ | max. 100       | mA               |
| $t_{gd}$         | $T_{vj} = 25$ °C; $I_G = 1$ A; $di_G/dt = 1$ A/μs       | 1              | μs               |
| $t_{gr}$         | $V_D = 0,67 * V_{DRM}$                                  | 2              | μs               |
| $(di/dt)_{cr}$   | $T_{vj} = 125$ °C                                       | max. 125       | A/μs             |
| $(dv/dt)_{cr}$   | $T_{vj} = 125$ °C                                       | max. 1000      | V/μs             |
| $t_q$            | $T_{vj} = 125$ °C                                       | 100 ... 250    | μs               |
| $I_H$            | $T_{vj} = 25$ °C; typ. / max.                           | 250 / 500      | mA               |
| $I_L$            | $T_{vj} = 25$ °C $R_G = 33 \Omega$ ; typ. / max.        | 0,5 / 2        | mA               |
| $V_{GT}$         | $T_{vj} = 25$ °C; d.c.                                  | min. 5         | V                |
| $I_{GT}$         | $T_{vj} = 25$ °C; d.c.                                  | min. 250       | mA               |
| $V_{GD}$         | $T_{vj} = 125$ °C; d.c.                                 | max. 0,25      | V                |
| $I_{GD}$         | $T_{vj} = 125$ °C; d.c.                                 | max. 10        | mA               |
| $R_{th(j-c)}$    | cont.; DSC  | 0,021          | K/W              |
| $R_{th(j-c)}$    | sin. 180; DSC / SSC                                     | 0,0225 / 0,054 | K/W              |
| $R_{th(j-c)}$    | rec. 120; DSC / SSC                                     | 0,027 / 0,06   | K/W              |
| $R_{th(c-s)}$    | DSC / SSC   | 0,005 / 0,01   | K/W              |
| $T_{vj}$         |   | - 40 ... + 125 | °C               |
| $T_{stg}$        |   | - 40 ... + 130 | °C               |
| $V_{isol}$       |   | -              | V~               |
| F                | mounting force  | 22 ... 25      | kN               |
| a                |   |                | m/s <sup>2</sup> |
| m                | approx.   | 550            | g                |
| Case             |   | B 14           |                  |



**SKT**







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